Fractional quantum Halle ect in higher Landau levels

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Abstract

We investigate, using nite size numerical calculations, the spin-polarized fractional quantum Halle ect (FQHE) in the rst excited Landau level (LL). We not evidence for the existence of an incompressible state at $=\frac{7}{3}=2+\frac{1}{3}$, but not at $=2+\frac{2}{5}$. Surprisingly, the 7/3 state is found to be strongest at a nite thickness. The structure of the low-lying excited states is found to be markedly di erent from that in the low-est LL. This study also rules out FQHE at a large number of odd-denom inator fractions in the lowest LL.

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A good m icroscopic understanding of the physics of the fractional quantum Halle ect (FQHE) in the lowest Landau level (LL) is provided by the composite ferm ion theory¹. It is straightforwardly explained as the integer quantum Halle ect (IQHE) of a novel kind of particles, namely composite ferm ions, composed of electrons bound to an even number of vortices. The recent experim ental observation of composite ferm ions by several groups² has given further support to this picture. Understanding of FQHE in the rst excited LL is not so satisfactory, how ever.

Several experiments have shown clear evidence of FQHE in the rst excited LL as well. Taking account of both spin-subbands of the lowest LL (LLL), the st excited LL corresponds to the exper-> 2. The rst observed fraction in this range was $=\frac{5}{2}=2+\frac{1}{2}^{3/4}$. im ental lling factor range 4 > The occurrence of an incompressible state at $=\frac{5}{2}$ is quite peculiar for several reasons. One, that there is no FQHE at $=\frac{1}{2}$, its counterpart in the LLL. In fact, recent experiments at $=\frac{1}{2}$ showed clear evidence of a Ferm i surface of spin-polarized composite ferm ions at this lling factor. Second, $=\frac{5}{2}$ is so far the only even denom inator fraction observed in single layer system s. F inally, exact nite size calculations, which involve only Coulomb interaction between electrons within one LL, do not seem to nd any incompressible state at this lling factor. Several attempts have been m ade to provide a theoretical understanding of this state. Haldane and Rezayi⁵ proposed a spin-singlet wave function for a $=\frac{5}{2}$ FQHE, which is valid for a hollow-core model interaction. The present authors proposed a di erent spin-singlet wave function, which is valid for a short-range, hard-core m odel interaction, and possesses the composite ferm ion structure⁶. Neither of these wave functions is a good representation of the Coulom b ground state, though. It is possible that inclusion of higher Landau level mixing might make one of these relevant to 5/2 FQHE. The present work only deals with fully polarized states.

Another fraction in higher LL at which FQHE has been observed is $=\frac{7}{3}=2+\frac{1}{3}$. Laughlin's successful wave function at $1/3^7$ has been generalized to $7/3^8$, but it does not provide a very satisfactory description of the 7/3 state, consistent with a relatively weak FQHE at this fraction. Our calculations con m this result for strictly two-dimensional (2D) systems. However, we not the surprising result that for wider quantum wells, the exact ground state becomes closer to the Laughlin state, and the FQHE at 7/3 becomes stronger; the energy gap acquires its maximum value when the thickeness is roughly equal to twice the magnetic length. This is in contrast to the situation in the lowest LL, where the FQHE is in general the strongest at zero thickness.

We model the nite thickeness e ects, in the square well con guration, by accounting for the spread of the one-electron wave function along the z-direction. (We have also studied the triangular hetero junction con nement; the results are sim ilar.) We restrict ourselves to the lowest subband; this approximation is not valid for large thicknesses, when the subband spacing is small, and interband transitions become important. In the square well geometry, the (unnormalized) z-component of the one-electron wave function in the lowest band is given by $(z) = \cos(z=d)$, where d is the thickeness of the well. The distances will be expressed in units of the magnetic length, .We make use of Haldane's pseudopotentials V_m ⁹, which are the energies of pairs of electrons with relative angularm on entum m :

$$V_{m} = \int_{0}^{Z_{1}} q dq \, \nabla (q) \, L_{n} \left(\frac{q^{2}}{2}\right)^{\#_{2}} L_{m} (q^{2}) e^{q^{2}} : \qquad (1)$$

where n denotes the LL index, and $\,\, \nabla \,$ (q) the electron-electron interaction in m om entum space given by

$$\nabla (q) = \frac{q^2}{q} \int_{-\infty}^{Z} dz_1 \int_{-\infty}^{Z} dz_2 j (z_1) j^2 j (z_2) j^2 e^{j z_1 z_2 j q}$$
(2)

It is convenient to write the C oulom b interaction in the form

$$\nabla (\mathbf{q}) = \frac{\mathbf{q}^2}{\mathbf{q}} \mathbf{F} (\mathbf{q}) \tag{3}$$

where the net e ect of nite thickeness is now summed up in the form factor F(q). In the case of a square well potential, it is given by¹⁰

$$F(q) = \frac{1}{x^2 + 4^2} \left[3x + \frac{8^2}{x} - \frac{32^4 (1 - \exp^x)}{x^2 (x^2 + 4^2)} \right]^{\#}; x = qd$$
(4)

O ur calculations are performed in the spherical geometry⁹, in which electrons move on the surface of a sphere under the in uence of a radial magnetic eld. The ux through the surface, N , measured in unit of the ux quantum $_0 = hc=e$, must be an integer. The degeneracy of the LL is N + 1 and increases by 2 for each successive LL. It is well known at what values of N various incompressible states (e.g. 1/3 and 2/5) occur in the LLL for nite system $s^{9;11}$. It is assumed that in the rst excited LL, 7/3 (12/5) occurs at that value of magnetic eld for which the degeneracy of the rst excited LL is equal to the degeneracy of the LLL at 1/3 (2/5). In all our calculations, we use the therm odynam ic values of V_m. Only electrons in a given LL are considered (i.e., LL m ixing is neglected), and it is assumed that they are fully polarized. W hile comparing the LLL state with the corresponding higher LL state, we use the standard prescription⁸ in which the LL index is changed before computing the overlaps. A susual, the eigenstates are labeled by their total orbital angular m on entum L.

O ur calculated energy spectra of 6 and 8 electrons at lling fractions of $\frac{7}{3}$ and $\frac{12}{5}$, respectively, are shown in Fig. 1. The two top gures correspond to lling factors 1/3 and 2/5 (in the lowest n = 0 LL) at zero thickness, while the rest of the gures correspond to 7/3 (left colum n) and 12/5 (right colum n) for di erent values of thickness. The spectra in the LLL have been explained in great detail using the composite ferm ion theory¹¹. At = $\frac{7}{3}$, the ground state is at L = 0, and appears to have a gap, which is sim ilar to the situation at 1/3. The collective m ode branch, however, seem s di erent from that at 1/3; it extends to sm aller L, and no clear roton m inim um may be identi ed. The spectrum at = $\frac{12}{5}$ looks completely di erent from that at = 2=5; even the ground state is not uniform. To lear m ore about the nature of the low lying states, we calculate their overlap with the corresponding states in the LLL, shown in gure 1. W hile the overlaps are poor for strictly 2D layers (d = 0), they increase appreciably as the thickness of the layers is increased. For = $\frac{12}{5}$ a level crossing transition occurs to a uniform (L = 0) ground state at around around d = 2, but there is no clear energy gap even at large widths.

We now study bigger system s, and focus on the nature of the incompressible ground state at $=\frac{7}{3}$ for an 8 electron system and at $=\frac{12}{5}$ for a 10 electron system. The sizes of the H ilbert spaces in the L_z = 0 sector are 8512 and 16660, respectively, and a Lanczos algorithm is used for obtaining the ground state. Figure 2-a shows the overlap of the $=\frac{7}{3}$ ground state with the LLL 1/3 ground state. At zero thickeness, the overlap is slightly below 0.8. As the sample thickness is increased, the overlap increases to 0.93 at d = 4. Notice that the overlap at d = 4 is slightly larger for N = 8 than for N = 6 shown in gure 1, suggesting that the large overlap is not a nite size e ect, and that the $=\frac{12}{5}$. Figure 2-b shows the overlap of the ground state at $=\frac{12}{5}$ for a 10 electron system with the ground state at 2/5. The overlap is extrem ely poor for all values of the thickeness, indicating that the relatively large overlap obtained for N = 6 was probably a nite size e ect, and that there is, in fact, no FQHE at 12/5 in the therm odynam ic lim it.

Of particular interest in the FQHE is the value of the energy gap of the incompressible states, since it is an experimentally accessible quantity. In particular, it was found experimentally¹² that the gap of the 1/3 state decreases rapidly with increasing thickness. Song He et. al^{13} investigated

this theoretically, and found that the gap decreases because both the Coulom b interaction and the incom pressible state becom e weaker as the thickness is increased, the latterm an ifested in the decreasing overlap of the ground state with the Laughlin state. In the rst excited LL the picture is quite di erent, since the two e ects compete: while the Coulom b interaction gets weaker, the overlap of the ground state with the Laughlin increases as a function of thickness. Figure 3 shows the energy gap for the 8 electron system as a function of thickness¹⁴; it attains its maximum value at d 2, which is about 40% larger than the d = 0 gap. It would be quite interesting to see experimentally this enhancement of the energy gap.

An insight into the qualitative di erence between the two LL's can be gained in terms of dimensionless scaled pseudopotentials¹³, de ned as

$$f_m = (V_3 \quad V_m) = (V_1 \quad V_3)$$
 (5)

They explicitly satisfy the property that they are invariant under a constant shift of $V_m \, ! \, V_m + C$, which neither alters the eigenstates nor the eigenenergies (m easured relative to the ground state energy). Furtherm ore, $f_1 = 1$ and $f_3 = 0$ are independent of V_m . The Laughlin 1/3 state is the exact ground state for a hard-core m odel in which all V_m 's are zero except V_1 ; i.e., when $f_1 = 1$ and all other f_m 's are zero. So the nonzero values of f_m characterize the deviation from the hard-core m odel, and thus from the Laughlin state. At = 1=3, the scaled pseudopotentials increase m onotonically with thickness¹³, as shown in gure 4-a, so that at large enough thicknesses, the deviation is so large that the Laughlin state is destroyed.

Figure 4-b shows the thickness dependence of the f_m in the n = 1 LL. For m = 7, f_m do not increase m onotonically, but rather decrease rst, m ark a soft m inimum, and then increase as a function of thickness. M oreover, f_5 , which has the dom inant e ect, decreases for all values of thickness. The deviation from the hard-core m odel is therefore reduced by nite thickness in the n = 1 LL, which helps understand why the overlap of the $=\frac{7}{3}$ state with the Laughlin state increases, and reaches a plateau at large thickness.

Since the composite ferm ion theory relates QHE in higher LL's to FQHE in the lower LL's, our study also puts strong constraints on which fractions may be observed in the LLL. The principal observed fractions in the LLL correspond to the IQHE of composite fermions; e.g., = n = (2n + 1)FQHE of electrons corresponds to = n IQHE of composite ferm ions. The FQHE of composite ferm ions will lead to new fractions for electrons. Let us assume very large Zeem an energy, i.e., spinless electrons, so that a lling factor in the rst excited LL corresponds to an overall lling factor of 1+ . Then, the prominent FQHE in the rst excited LL is expected to occur at are = 1 + n = (2n + 1)n=(2n + 1). FQHE of composite fermions at these lling factors corresponds to FQHE and = 2of electrons in the LLL at = (3n + 1) = (8n + 3) and = (3n + 2) = (8n + 5), respectively. Our study shows that no FQHE can occur for n 2. In other words, the only states between 1/3 and 2/5 where FQHE may occur are 4/11 and 5/13 (which correspond to n = 1). Since 1/3 is already quite weak in the rst excited LL, it is likely that no FQHE is observed in third and higher LL's, which leads to the prediction that no FQHE states other than n = (2n + 1) are possible in the lling factor range 2=5 1=2. These predictions are generally consistent with experiments; there is some evidence for 4/11, but no other non-n=(2n + 1) fractions have been observed in this range. These considerations can be easily generalized to other regions of lling factors.

In conclusion, we have found that fractional quantum Halle ect occurs only at $=\frac{1}{3}$ and $=\frac{2}{3}$ in the rst excited LL, and that it is strongest at a nite thickness. We thank Professor A. MacD on ald for fruitful comments on this work. This work was supported by the NSF under Grant no. DMR 9318739.

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- 14 T he gap is computed from the size of the cusp at 7/3.
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FIGURES

FIG.1. Energy spectra of the low lying states for 6 (left column) and 8 (right column) electrons. The two top spectra are in the lowest (n = 0) LL, and the rest in the rst excited (n = 1) LL. The lling factor and the width are shown above each spectrum. The energies are given in units of $e^2 = .$

FIG.2. (a) Overlap of the ground state wave function at $=\frac{7}{3}$ (1/3 in the rst excited LL), with the ground state in lowest LL for 8 electrons. (a) Overlap of the ground state wave function at $=\frac{12}{5}$ (2/5 in the rst excited LL), with the ground state in lowest LL for 10 electrons.

FIG.3. Energy gap of $=\frac{7}{3}$ as a function of thickness.

FIG.4. The scaled pseudopotentials, de ned in the text, as a function of thickness for (a) the lowest and (b) the rst excited LL.